

2SD655

Silicon NPN Epitaxial

REJ03G0768-0200
(Previous ADE-208-1136)
Rev.2.00
Aug.10.2005

Application

Low frequency power amplifier, Muting

Outline

RENESAS Package code: PRSS0003DA-A
(Package name: TO-92 (1))



- 1. Emitter
- 2. Collector
- 3. Base

Absolute Maximum Ratings

(Ta = 25°C)

Item	Symbol	Ratings	Unit
Collector to base voltage	V_{CBO}	30	V
Collector to emitter voltage	V_{CEO}	15	V
Emitter to base voltage	V_{EBO}	5	V
Collector current	I_C	0.7	A
Collector peak current	$i_{C(peak)}$	1.0	A
Collector power dissipation	P_C	500	mW
Junction temperature	T_j	150	°C
Storage temperature	T_{stg}	-55 to +150	°C

Electrical Characteristics

(Ta = 25°C)

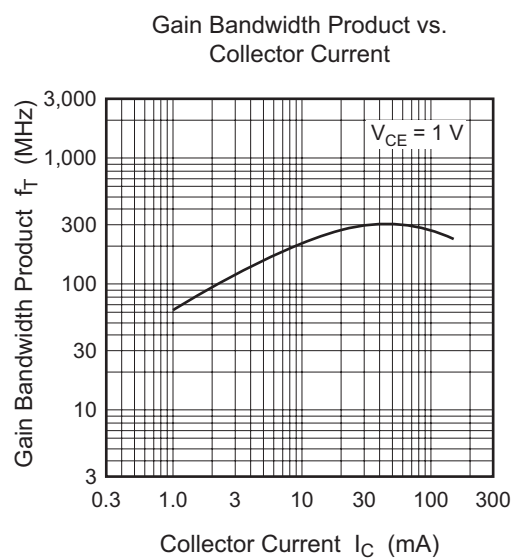
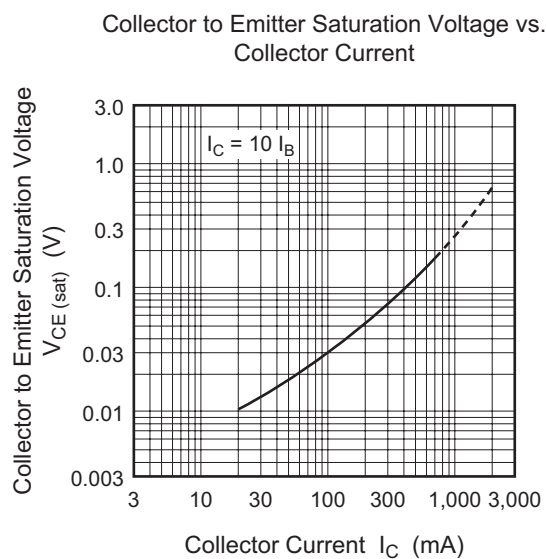
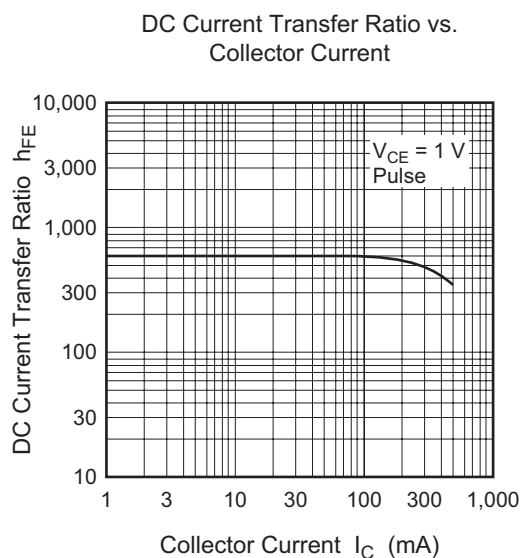
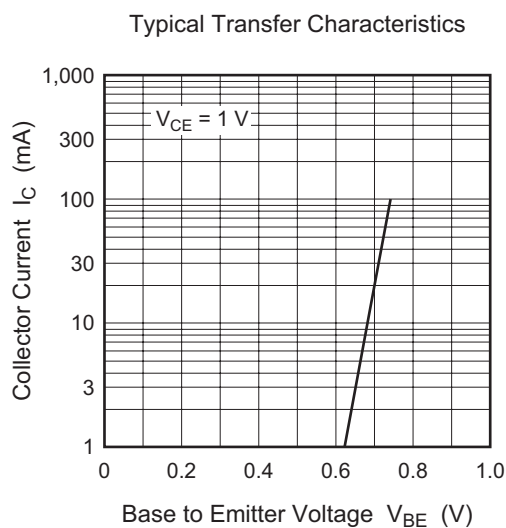
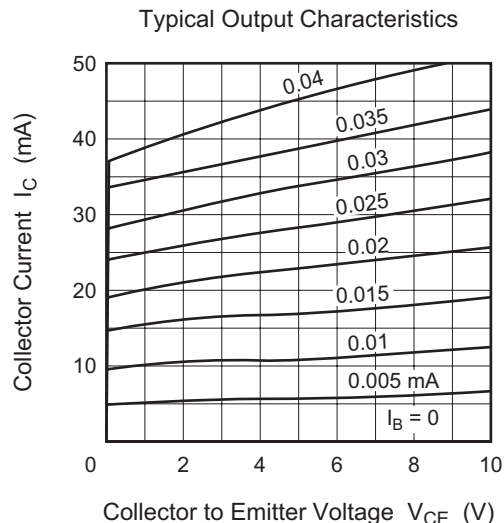
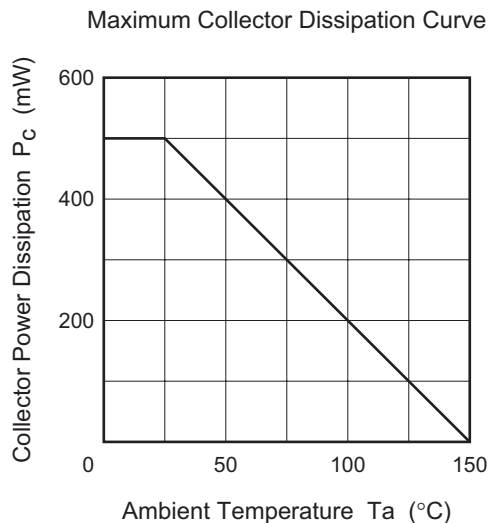
Item	Symbol	Min	Typ	Max	Unit	Test conditions
Collector to base breakdown voltage	$V_{(BR)CBO}$	30	—	—	V	$I_C = 10\ \mu A, I_E = 0$
Collector to emitter breakdown voltage	$V_{(BR)CEO}$	15	—	—	V	$I_C = 1\ mA, R_{BE} = \infty$
Emitter to base breakdown voltage	$V_{(BR)EBO}$	5	—	—	V	$I_E = 10\ \mu A, I_C = 0$
Collector cutoff current	I_{CBO}	—	—	1.0	μA	$V_{CB} = 20\ V, I_E = 0$
Base to emitter voltage	V_{BE}	—	—	1.0	V	$V_{CE} = 1\ V, I_C = 150\ mA$
Collector to emitter saturation voltage	$V_{CE(sat)}$	—	0.15	0.5	V	$I_C = 500\ mA, I_B = 50\ mA^{*2}$
DC current transfer ratio	h_{FE}^{*1}	250	—	1200		$V_{CE} = 1\ V, I_C = 150\ mA^{*2}$
Gain bandwidth product	f_T	—	250	—	MHz	$V_{CE} = 1\ V, I_C = 150\ mA$

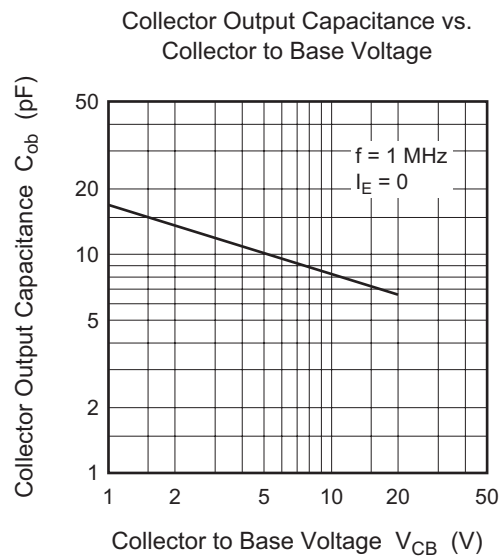
Notes: 1. The 2SD655 is grouped by h_{FE} as follows.

2. Pulse test

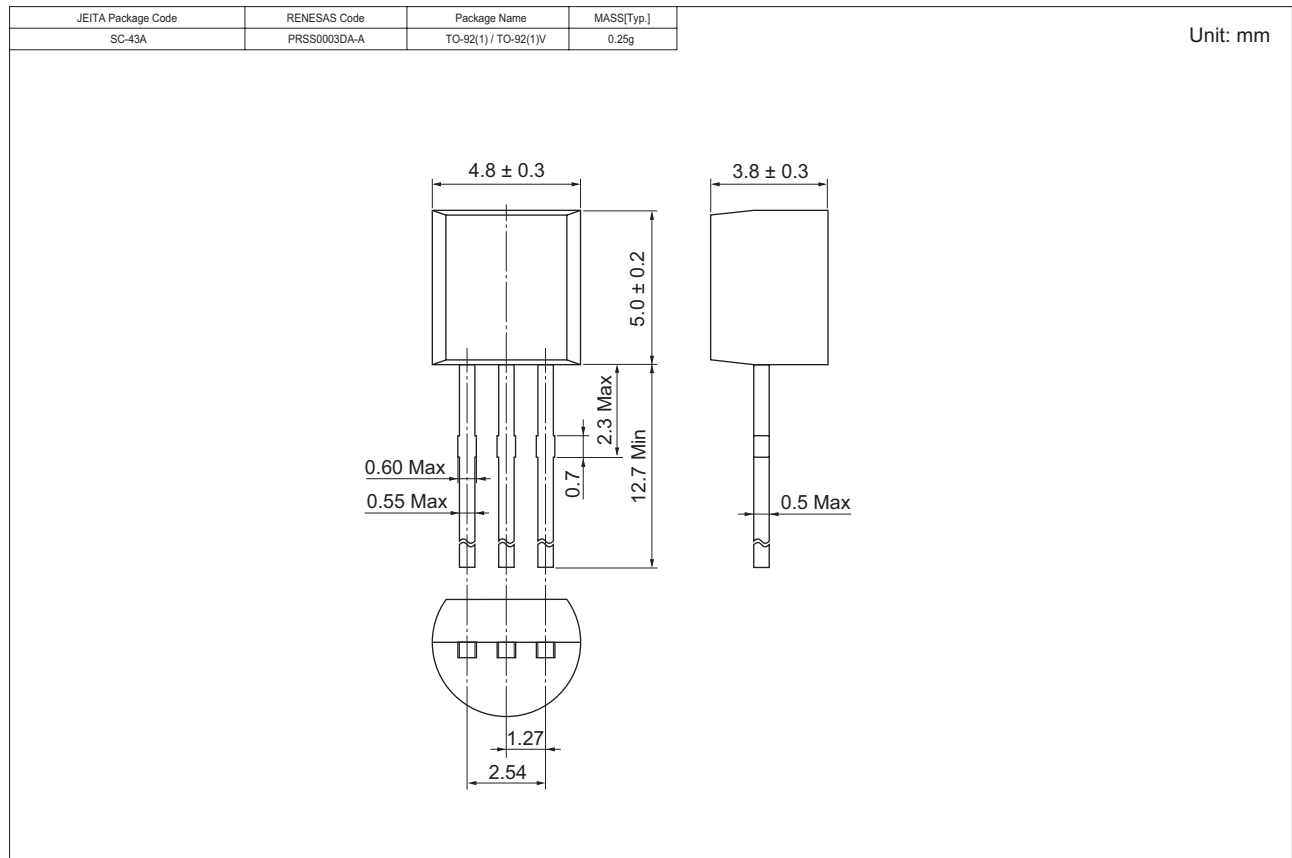
D	E	F
250 to 500	400 to 800	600 to 1200

Main Characteristics





Package Dimensions



Ordering Information

Part Name	Quantity	Shipping Container
2SD655DTZ-E	2500	Hold Box, Radial Taping
2SD655ETZ-E		
2SD655FTZ-E		

Note: For some grades, production may be terminated. Please contact the Renesas sales office to check the state of production before ordering the product.

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